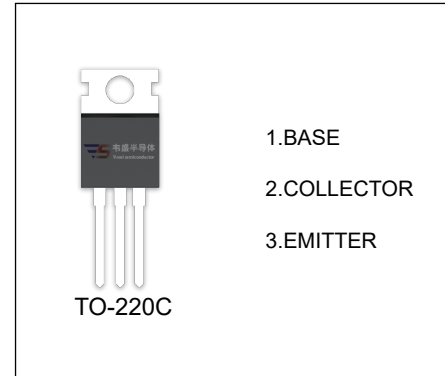


## 2SD2012 TRANSISTOR (NPN)

### FEATURES

- High DC Current Gain
- Low Saturation Voltage
- High Power Dissipation



### MAXIMUM RATINGS ( $T_a=25^{\circ}\text{C}$ unless otherwise noted)

| Symbol          | Parameter  | Value    | Unit                        |
|-----------------|--|----------|-----------------------------|
| $V_{CBO}$       | Collector-Base Voltage                           | 60       | V                           |
| $V_{CEO}$       | Collector-Emitter Voltage                        | 60       | V                           |
| $V_{EBO}$       | Emitter-Base Voltage                             | 7        | V                           |
| $I_C$           | Collector Current                                | 3        | A                           |
| $P_C$           | Collector Power Dissipation                      | 2        | W                           |
| $R_{\theta JA}$ | Thermal Resistance From Junction To Ambient      | 63       | $^{\circ}\text{C}/\text{W}$ |
| $T_J, T_{stg}$  | Operation Junction and Storage Temperature Range | -55~+150 | $^{\circ}\text{C}$          |

### ELECTRICAL CHARACTERISTICS ( $T_a=25^{\circ}\text{C}$ unless otherwise specified)

| Parameter                            | Symbol        | Test conditions                           | Min | Typ | Max | Unit          |
|--------------------------------------|---------------|---|-----|-----|-----|---------------|
| Collector-base breakdown voltage     | $V_{(BR)CBO}$ | $I_C=100\mu\text{A}, I_E=0$               | 60  |     |     | V             |
| Collector-emitter breakdown voltage  | $V_{(BR)CEO}$ | $I_C=50\text{mA}, I_B=0$                  | 60  |     |     | V             |
| Emitter-base breakdown voltage       | $V_{(BR)EBO}$ | $I_E=100\mu\text{A}, I_C=0$               | 7   |     |     | V             |
| Collector cut-off current            | $I_{CBO}$     | $V_{CB}=60\text{V}, I_E=0$                |     |     | 100 | $\mu\text{A}$ |
| Emitter cut-off current              | $I_{EBO}$     | $V_{EB}=7\text{V}, I_C=0$                 |     |     | 100 | $\mu\text{A}$ |
| DC current gain                      | $h_{FE(1)}$   | $V_{CE}=5\text{V}, I_C=0.5\text{A}$       | 100 |     | 320 |               |
|                                      | $h_{FE(2)}$   | $V_{CE}=5\text{V}, I_C=2\text{A}$         | 20  |     |     |               |
|                                      | $h_{FE(3)}$   | $V_{CE}=5\text{V}, I_C=3\text{A}$         | 60  |     |     |               |
| Collector-emitter saturation voltage | $V_{CE(sat)}$ | $I_C=2\text{A}, I_B=0.2\text{A}$          |     |     | 1   | V             |
| Base-emitter voltage                 | $V_{BE}$      | $V_{CE}=5\text{V}, I_C=0.5\text{A}$       |     |     | 1   | V             |
| Collector output capacitance         | $C_{ob}$      | $V_{CB}=10\text{V}, I_E=0, f=1\text{MHz}$ |     | 35  |     | pF            |
| Transition frequency                 | $f_T$         | $V_{CE}=5\text{V}, I_C=0.5\text{A}$       |     | 3   |     | MHz           |

\*Pulse test

